

RS3AF THRU RS3MF

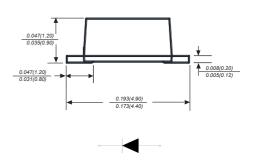
Reverse Voltage - 50 to 1000 Volts Forward Current - 3.0 Ampere

SURFACE MOUNT FAST RECOVERY RECTIFIER

Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Fast switching for high efficiency
- Low reverse leakage
- ◆ Built-in strain relief,ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed: 260°C/10 seconds at terminals
 Glass passivated chip junction

SMAF ROHS COMPLIANT 0.063 (1.60) 0.061 (1.30) 0.094(2.40) 0.146(3.70) 0.130(3.30)



Dimensions in inches and (millimeters)

Mechanical Data

Case: JEDEC DO-214AC/SMAF Molded plastic body

Terminals: Solder plated, solderable per MIL-STD-750, Method 2026

Polarity: Polarity symbol marking on body

Mounting Position: Any

Weight: 0.00095ounce, 0.027 grams

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unlss otherwise specified.

Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

Parameter		RS3AF	RS3BF	RS3DF	RS3GF	RS3JF	RS3KF	RS3MF	
Marking Code	SYMBOLS	MDD RS3AF	MDD RS3BF	MDD RS3DF	MDD RS3GF	MDD RS3JF	MDD RS3KF	MDD RS3MF	UNITS
Maximum repetitive peak reverse voltage	VRMM	50	100	200	400	600	800	1000	V
Maximum RMS voltage	VRMS	35	70	140	280	420	560	700	V
Maximum DC blocking voltage	VDC	50	100	200	400	600	800	1000	V
Maximum average forward rectified current at TL=90 ℃	l(AV)	3.0						А	
Peak forward surge current									
8.3ms single half sine-wave	Ігѕм				50				Α
superimposed onrated load (JEDEC Method)									
Maximum instantaneous forward voltage at 3.0A	VF	1.30					V		
Maximum DC reverse current TA=25°C at rated DC blocking voltage TA=125°C	lR	5.0 200				uA			
Maximum reverse recovery time (NOTE 1)	trr		15	50		250	50	00	ns
Typical junction capacitance (NOTE 2)	Сл	60.0			pF				
Typical thermal resistance (NOTE 3)	Rθja	20.0					°C/W		
Operating junction and storage temperature range	ТЈ,Тѕтс	-55 to +150					°C		

Note:1.Reverse recovery condition IF=0.5A,IR=1.0A,Irr=0.25A

2.Measured at 1MHz and applied reverse voltage of 4.0V D.C.

3.P.C.B. mounted with 0.2x0.2"(5.0x5.0mm) copper pad areas

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Ratings And Characteristic Curves

Fig.1 Forward Current Derating Curve

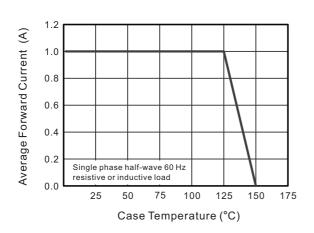


Fig.2 Typical Reverse Characteristics

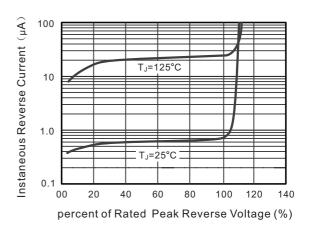


Fig.3 Typical Instaneous Forward Characteristics

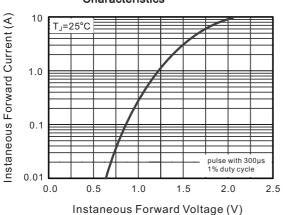


Fig.4 Typical Junction Capacitance

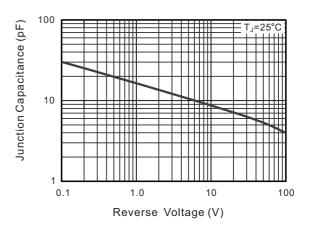
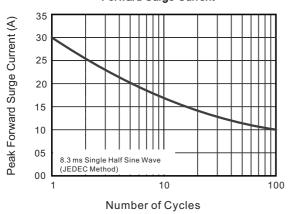


Fig.5 Maximum Non-Repetitive Peak Forward Surge Current



The curve above is for reference only.

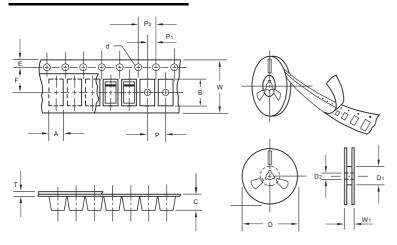
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Packing information



ltem	Symbol	Tolerance	SMAF
Carrier width	A	0.1	2.80
Carrier length	В	0.1	4.75
Carrier depth	С	0.1	1.42
Sprocket hole	d	0.05	1.50
7" Reel outside diameter	D	2.0	178.00
7" Reel inner diameter	D1	min	54.40
Feed hole diameter	D2	0.5	13.00
Sprocket hole position	E	0.1	1.75
Punch hole position	F	0.1	5.05
Punch hole pitch	Р	0.1	4.00
Sprocket hole pitch	Po	0.1	4.00
Embossment center	P1	0.1	2.00
Overall tape thickness	T	0.1	0.30
Tape width	W	0.3	8.00
Reel width	W1	1.0	12.30

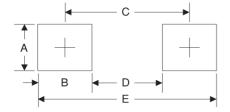
unit:mm

Note: Devices are packed in accor dance with EIA standar RS-481-A and specifications listed above.

Reel packing

PACKAGE	REEL SIZE	REEL (pcs)	COMPONENT SPACING (m/m)	BOX (pcs)	INNER BOX (m/m)	REEL DIA, (m/m)	CARTON SIZE (m/m)	CARTON (pcs)	APPROX. GROSS WEIGHT (kg)
SMAF	7"	3,000	4.0	6,000	210*208*203	178	400*265*400	120,000	10.0

Suggested Pad Layout



Symbol	Unit (mm)	Unit (inch)
Α	1.8	0.071
В	1.6	0.063
С	3.8	0.150
D	2.2	0.087
Е	5.4	0.213

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